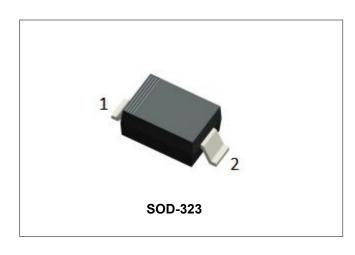






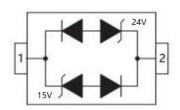
## SD1524LCC TVS Array



#### **Features**

- ESD protection of one automotive LIN bus line
- Asymmetrical diode configuration ensures an optimized Electromagnetical Immunity of a LIN Electronic Control Unit (ECU)
- Due to the integrated diode structure only one very small SOD323 package is needed
- ESD protection of up to 23 kV
- IEC 61000-4-2, level 4 (ESD)
- IEC 61000-4-5 (surge); IPP = 3 A at tp = 8/20μs
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- . All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

#### **Schematic & Pin Configuration**



| Pin | Description      |  |
|-----|------------------|--|
| 1   | cathode 1 (15 V) |  |
| 2   | cathode 2 (24 V) |  |

#### **Mechanical Characteristics**

- Case: SOD-323, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208

#### Maximum Ratings@T<sub>A</sub>=25°C unless otherwise specified

| Parameter                           | Symbol | Value      | Unit |
|-------------------------------------|--------|------------|------|
| Peak Pulse Power (tp=8/20 μ s)      | Ppp    | 160        | W    |
| Peak Pulse Current (tp=8/20 μ s)    | Ірр    | 3          | Α    |
| Operating Storage Temperature Range | Тѕтс   | -65 to 150 | °C   |
| Operating Junction Temperature      | TJ     | 150        | °C   |

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •







# Electrical Characteristics@T<sub>A</sub>=25°C unless otherwise specified

| Characteristics           | Symbol           | Condition                  | Min. | Тур. | Max. | Units |
|---------------------------|------------------|----------------------------|------|------|------|-------|
| Breakdown Voltage*        | $V_{BR}$         | IR=5mA, SD1524LCC(15V)     | 17.1 | 18.9 | 20.3 | V     |
| _                         | V BR             | SD1524LCC(24V)             | 25.4 | 27.8 | 30.3 |       |
| Reverse Standoff Voltage* | V <sub>RWM</sub> | SD1524LCC(15V)             |      |      | 15.0 | V     |
| Reverse Standon Voltage   | V RWM            | SD1524LCC(24V)             | •    | -    | 24.0 |       |
| Reverse Leakage Current*  | IRM              | VR=15V, SD1524LCC(15V)     |      | -    | 50   | nA    |
| _                         | IRM              | VR=24V, SD1524LCC(24V)     | -    |      | 50   | IIA   |
| Clamp Voltage             | Vc               | Ipp=1A tp=8/20µs           | -    | -    | 25   | V     |
| SD1524LCC(15V)            | V <sub>C</sub>   | Ipp=5A tp=8/20µs           | -    | -    | 44   | V     |
| Clamp Voltage             | Vc               | Ipp=1A tp=8/20μs           | -    | -    | 40   | V     |
| SD1524LCC(24V)            | VC               | Ipp=3A tp=8/20µs           | -    | -    | 70   | V     |
| Diode Capacitance         | C <sub>D</sub>   | Reverse Bias=0V, f = 1 MHz | -    | -    | 17   | pF    |

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%







### **Ratings and Characteristics Curves**

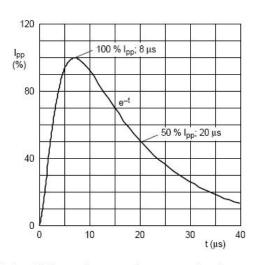


Fig 1. 8/20  $\mu$ s pulse waveform according to IEC 61000-4-5.

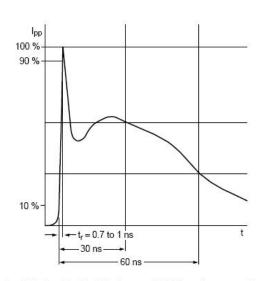
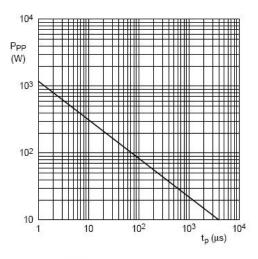


Fig 2. ElectroStatic Discharge (ESD) pulse waveform according to IEC 61000-4-2.



T<sub>amb</sub> = 25 °C.

 $t_p$  = 8/20  $\mu$ s exponentially decaying waveform; see Figure 1

Fig 3. Peak pulse power dissipation as a function of pulse time; typical values.

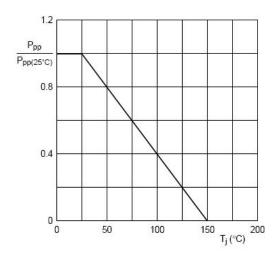


Fig 4. Relative variation of peak pulse power as a function of junction temperature; typical values.





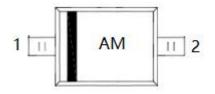


### **Ordering Information**

| Device      | Package          | Shipping       |
|-------------|------------------|----------------|
| SD1524LCC   | SOD-323(Pb-Free) | 3000pcs / reel |
| SD1524LCCTR | SOD-323(Pb-Free) | 3000pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

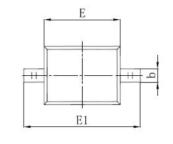
### **Marking Diagram**

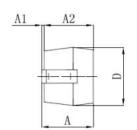


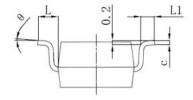
Where AM is SD1524LCC

AM = Marking code

### **Mechanical Dimensions SOD-323**

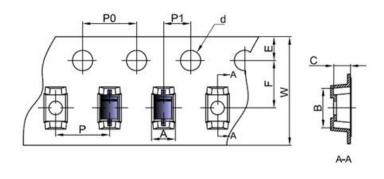






| OVMDOL | Millim     | neters | Inches |       |  |
|--------|------------|--------|--------|-------|--|
| SYMBOL | MIN.       | MAX.   | MIN.   | MAX.  |  |
| Α      | -          | 1.000  | -      | 0.039 |  |
| A1     | 0.000      | 0.100  | 0.000  | 0.004 |  |
| A2     | 0.800      | 0.900  | 0.031  | 0.035 |  |
| b      | 0.250      | 0.350  | 0.010  | 0.014 |  |
| С      | 0.080      | 0.150  | 0.003  | 0.006 |  |
| D      | 1.200      | 1.400  | 0.047  | 0.055 |  |
| Е      | 1.600      | 1.800  | 0.063  | 0.071 |  |
| E1     | 2.500      | 2.700  | 0.098  | 0.106 |  |
| L      | 0.475 REF. |        | 0.019  | REF.  |  |
| L1     | 0.250      | 0.400  | 0.010  | 0.016 |  |
| θ      | 0°         | 8°     | 0°     | 8°    |  |

### **Carrier Tape Specification SOD-323**



| SYMB | Millimeters |      |  |  |
|------|-------------|------|--|--|
| OL   | Min.        | Max. |  |  |
| В    | 2.85        | 2.95 |  |  |
| O    | 1.20        | 1.30 |  |  |
| d    | 1.40        | 1.60 |  |  |
| Е    | 1.65        | 1.85 |  |  |
| F    | 3.40        | 3.60 |  |  |
| Р    | 3.90        | 4.10 |  |  |
| P0   | 3.90        | 4.10 |  |  |
| P1   | 1.90        | 2.10 |  |  |
| W    | 7.90        | 8.30 |  |  |

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •







#### DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Diode Solutions.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..